Formosa MS

FM5817-L THRU FM5819-L

List

_ist	1
Package outline	2
eatures	2
Mechanical data	2
Maximum ratings	2
Rating and characteristic curves	3
Pinning information	.4
Marking	4
Suggested solder pad layout	4
Packing information	. 5
Reel packing	6
Suggested thermal profiles for soldering processes	. 6
High reliability test capabilities	.7

Formosa MS

FM5817-L THRU FM5819-L

1.0A Surface Mount Schottky Barrier Rectifiers - 20V-40V

Features

- Batch process design, excellent power dissipation offers better reverse leakage current and thermal resistance.
- Low profile surface mounted application in order to optimize board space.
- Low power loss, high efficiency.
- High current capability, low forward voltage drop.
- High surge capability.
- Guardring for overvoltage protection.
- Ultra high-speed switching.
- Silicon epitaxial planarchip, metal siliconjunction.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

Mechanical data

• Epoxy:UL94-V0 rated flame retardant

• Case: Molded plastic, DO-214AC/SMA-L

• Terminals: Solder plated, solderable per

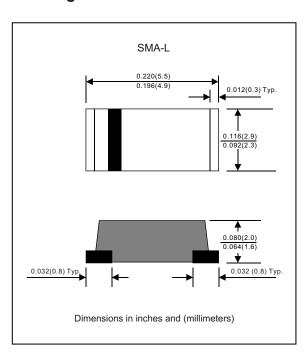
MIL-STD-750, Method 2026

• Polarity: Indicated by cathode band

• Mounting Position : Any

• Weight: Approximated 0.05 gram

Package outline



Maximum ratings (AT T_A=25°C unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current	See Fig.2	Io			1.0	Α
Forward surge current	8.3ms single halfsine-wave superimposed on rate load (JEDEC methode)	I _{FSM}			30	А
	$V_R = V_{RRM} T_A = 25^{\circ}C$				0.5	A
Reverse current	$V_R = V_{RRM} T_A = 125$ °C	I _R			10	mA
Thermal resistance	Junction to ambient	R _{eJA}		80		°C/W
Diode junction capacitance	f=1MHz and applied4V DC reverse voltage	C¹		130		pF
Storage temperature		T _{stg}	-65		+175	°C

SYMBOLS	V _{RRM} *1 (V)	V _{RMS} *2	V _R *3 (V)	V _F *4 (V)	Operating temperature T _J , (°C)
FM5817-L	20	14	20	0.45	
FM5818-L	30	21	30	0.50	-55 to +125
FM5819-L	40	28	40	0.50	

- *1 Repetitive peak reverse voltage
- *2 RMS voltage
- *3 Continuous reverse voltage
- *4 Maximum forward voltage

Document ID	Issued Date	RevisedDate	Revision	Page.
DS-121617	2008/02/10	2009/05/07	С	7

Rating and characteristic curves (FM5817-L THRU FM5819-L)

FORWARD VOLTAGE,(V)

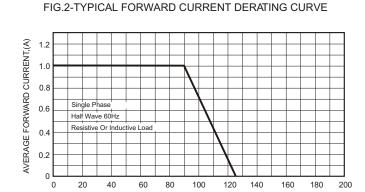
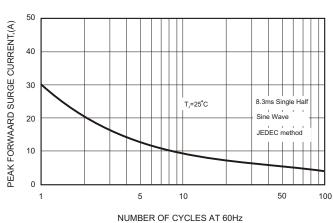
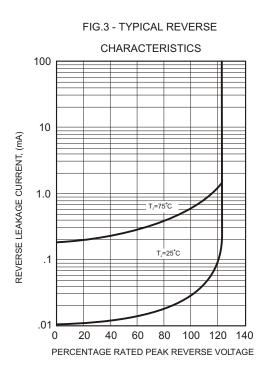
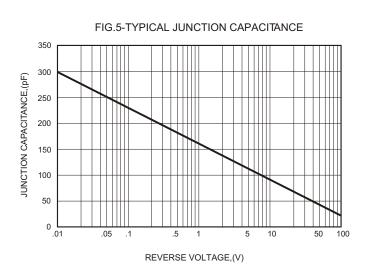


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

AMBIENT TEMPERATURE (°C)









FM5817-L THRU FM5819-L

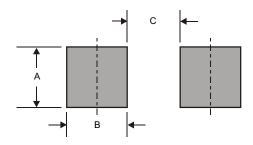
Pinning information

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode	1 2	1 2

Marking

Type number	Marking code
FM5817-L FM5818-L	SK12 SK13
FM5819-L	SK14

Suggested solder pad layout



Dimensions in inches and (millimeters)

PACKAGE	Α	В	С	
SMA-L	0.110 (2.80)	0.059 (1.50)	0.110 (2.80)	

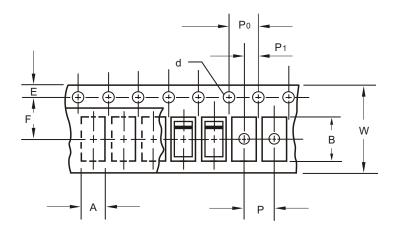


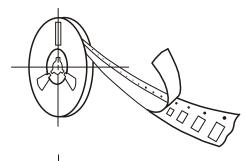
Document ID	Issued Date	RevisedDate	Revision	Page.
DS-121617	2008/02/10	2009/05/07	С	7

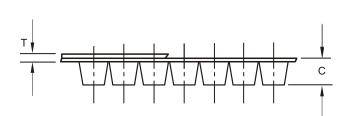
Formosa MS

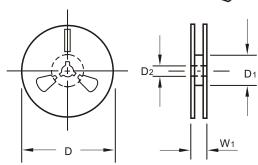
FM5817-L THRU FM5819-L

Packing information









unit:mm

Item	Symbol	Tolerance	SMA-L
Carrier width	Α	0.1	2.90
Carrier length	В	0.1	5.50
Carrier depth	С	0.1	2.10
Sprocket hole	d	0.1	1.50
13" Reel outside diameter	D	2.0	330.00
13" Reel inner diameter	D1	min	50.00
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D1	min	62.00
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	Е	0.1	1.75
Punch hole position	F	0.1	5.50
Punch hole pitch	Р	0.1	4.00
Sprocket hole pitch	P ₀	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	Т	0.1	0.23
Tape width	W	0.3	12.00
Reel width	W1	1.0	18.00

Note: Devices are packed in accor dance with EIA standar RS-481-A and specifications listed above.



Document ID	Issued Date	RevisedDate	Revision	Page.
DS-121617	2008/02/10	2009/05/07	С	7



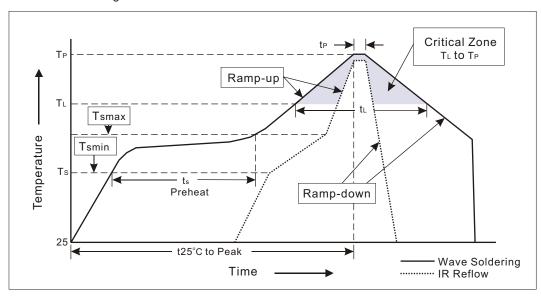
FM5817-L THRU FM5819-L

Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SMA-L	7"	2,000	4.0	20,000	183*170*183	178	382*356*387	160,000	15.5
SMA-L	13"	7,500	4.0	15,000	337*337*37	330	350*330*360	120,000	14.2

Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=10°C~35°C Humidity=65%±15%
- 2.Reflow soldering of surface-mount devices



3. Flow (wave) soldering (solder dipping)

Profile Feature	Soldering Condition
Average ramp-up rate(T∟ to T♭)	<3°C/sec
Preheat -Temperature Min(Tsmin) -Temperature Max(Tsmax) -Time(min tomax)(ts)	100°C 150°C 60~120sec
Tsmaxto T∟ -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(TL) -Time(tL)	183°C 60~150sec
Peak Temperature(T _P)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(₺)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes



FM5817-L THRU FM5819-L

High reliability test capabilities

Item Test	Conditions	Reference
1. Solder Resistance	at 260±5°C for 10±2sec. immerse body into solder 1/16"±1/32"	MIL-STD-750D METHOD-2031
2. Solderability	at 245±5°C for 5 sec.	MIL-STD-202F METHOD-208
3. High Temperature Reverse Bias	V_R =80% rate at T_J =125°C for 168 hrs.	MIL-STD-750D METHOD-1026
4. Forward Operation Life	Rated average rectifier current at T=25°C for 500hrs.	MIL-STD-750D METHOD-1027
5. Intermittent Operation Life	$T_A = 25^{\circ}$ C, $I_F = I_{\circ}$ On state: poweron for 5 min. off state: power off for 5 min. on and off for 500 cycles.	MIL-STD-750D METHOD-1036
6. Pressure Cooker	$15P_{SIG}$ at $T_A=121^{\circ}C$ for 4 hrs.	
7. Temperature Cycling	-55°C to +125°C dwelled for 30 min. and transferred for 5 min. total 10 cycles.	MIL-STD-750D METHOD-1051
8. Thermal Shock	0°C for 5min. rise to 100°C for 5min. total 10 cycles.	MIL-STD-750D METHOD-1056
9. Forward Surge	8.3ms single halfsine-wave superimposed on rated load, one surge.	MIL-STD-750D METHOD-4066-2
10. Humidity	at T _A =65°C, RH=98% for1000hrs.	MIL-STD-750D METHOD-1038
11. High Temperature Storage Life	at 175°C for 1000 hrs.	MIL-STD-750D METHOD-1031
12. Solvent Resistance	Dip into Freonat 25°C for 1 min.	MIL-STD-202F METHOD-215